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A comprehensive exploration of Na⁺ ion transport in NaSICONs using molecular dynamics simulations†

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Scandium-substituted $Na_{1+x+y}Sc_yZr_{2-y}Si_xP_{3-x}O_{12}$ NaSICONs have emerged as promising electrolyte materials for all-solid-state sodium batteries. However, the comprehensive investigation of these multi-element structures is challenging due to their vast compositional space, leading to a limited number of compositions explored thus far. In this study, we address this issue by employing low-cost, yet high-precision force field molecular dynamics simulations based on density functional theory to investigate the Na⁺ mobility and resulting conductivity in $Na_{1+x+y}Sc_yZr_{2-y}Si_xP_{3-x}O_{12}$ ($0 \leq x \leq 3$; $0 \leq y \leq 2$). Our findings show that the incorporation of Sc^{3+}- and Si^{4+}-substituents enhances the conductivity, achieving values of 10^{-2} S cm⁻¹ at room temperature for moderate to high substitution degrees. Moreover, our study demonstrates the efficacy of the applied methodology for large-scale screening, enabling the exploration of extensive configurational spaces of NaSICONs and other materials for potential use as solid-state electrolytes.

1. Introduction

Sodium-based energy storage systems have a longstanding history, but it is only in recent years that they stepped into the spotlight as concerns about limited resource availability of the market-dominating lithium-ion batteries prompted exploration of alternative solutions.[1–4] Sodium-ion batteries (NIBs) hold great promise as they provide a broad range of new possibilities, particularly for large-scale energy storage applications owing to the similar chemical properties of sodium and lithium, the abundance of sodium resources, and potential cost reduction.[1–15] Meanwhile, all-solid-state batteries (ASS) are being considered as the next generation of batteries due to their prolonged lifetimes, wide temperature ranges, and high energy and power densities.[16–26]

The performance of ASS batteries depends crucially on the applied solid-state electrolyte (SSE), which must provide high conductivity at ambient temperatures. Among Na⁺-based SSEs,

sodium superionic conductors (NaSICONs) have garnered significant attention, given their good thermal and (electro-) chemical stability, high ionic conductivity, and promising performance for ASS-NIBs.[17–22,27–40] Several articles provide an overview of the developments of NaSICONs.[41–49] The parent NaSICON composition $Na_{1+x}Zr_2Si_xP_{3-x}O_{12}$ (NZSP) exhibits the rhombohedral ($R\bar{3}c$) structure above 150 °C, but undergoes a monoclinic ($C2/c$) phase transformation for $1.6 \leq x \leq 2.4$ at room temperature.[50–58] As shown in Fig. 1a, the structure consists of a rigid three-dimensional framework composed of corner-sharing ZrO_6-octahedra and PO_4-tetrahedra, between which Na1 (6b) and Na2 (18e) sodium ion sites are located. In the non-substituted structure ($x = 0$), the energetically more
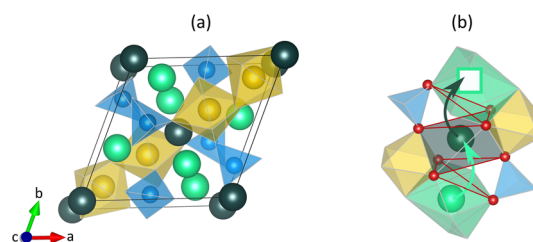
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† Electronic supplementary information (ESI) available. See DOI: https://doi.org/10.1039/d5ra01549a

Fig. 1 (a) The primitive rhombohedral structure of NaSICONs with composition $Na_{1+x}Zr_2Si_xP_{3-x}O_{12}$. (b) The correlated Na⁺ pushing-out conduction mechanism, indicated by arrows. One Na2 ion jumps onto an occupied Na1 site pushing the Na1 ion onto an adjacent unoccupied Na2 site. Key: Na1 (dark green), Na2 (light green), ZrO_6 (yellow), PO_4/SiO_4 (blue).

favorable Na1 sites are fully occupied. As the P^{5+} sites are substituted by Si^{4+}, the Na2 site occupation increases to satisfy the overall charge neutrality.[50,51,54,55,57–67] The diffusion of the Na^+ charge carriers is based on the correlated knock-off mechanism which involves the potential energy transfer from higher energy Na2 ions to lower energy Na1 ions.[68] This diffusion mechanism has already been proposed and studied in detail for various Na^+ and Li^+ conductors, such as NaSICONs,[68–70] garnets,[68] and Li_2CO_3.[71] As illustrated in Fig. 1b, a Na2 ion jumps onto an adjacent occupied Na1 site and pushes the Na1 ion onto a neighboring unoccupied Na2 site. The bottlenecks of the migration are formed by opposing ZrO_6-octahedra and PO_4-tetrahedra adjacent to the pathway.[50,51,55,60,61,63,65,72–79]

The three-dimensional Na^+ mobility results in high ionic conductivities, *e.g.* up to 5.2×10^{-3} S cm^{-1} for $Na_{3.4}Zr_2Si_{2.4}P_{0.6}O_{12}$ at room temperature.[33] However, NZSP is associated with a number of challenges. First, obtaining stoichiometric pure compositions is difficult due to the formation of secondary phases, such as ZrO_2. Second, the microstructure depends strongly on the sample preparation method. Both aspects have significant impact on the ionic conductivity.[21,45,80]

Thus, numerous efforts in the past have been made to further improve NaSICONs in competition with liquid electrolytes. An outstanding feature of NaSICONs with the general formula $NaM_2(AO_4)_3$ is the ability of accommodating a wide range of M and A cations in the structural framework,[49] making multi-element substitution a feasible strategy for enhancing the performance of NaSICONs. For example, the substitution of Zr^{4+} by Sc^{3+} in NZSP leads to the suppression of secondary phases, optimization of the microstructure, and thus high Na^+ conductivities.[81–94] Ma *et al.* reported a remarkable total conductivity of 4.0×10^{-3} S cm^{-1} for $Na_{3.4}Sc_{0.4}Zr_{1.6}Si_2P_1O_{12}$ at room temperature.[81] In addition, Sc^{3+}-substituted structures exhibit a wide electrochemical stability window, suggesting both the application of high voltage cathode materials and the direct utilization of sodium metal anodes to boost the energy density.[35,81]

However, the multi-element substitution of NaSICONs results in a vast compositional search space that requires fast, low-cost methods for investigating Na^+ mobility and resulting conductivity. In this regard, computational techniques, such as molecular dynamics (MD) simulations, have proven as a powerful tool. MD provides comprehensive structural information and the dynamic evolution of conducting systems without relying on prior assumptions about the migration mechanism and pathways. Ionic jump events are directly observed from the modelled real-time dynamics and trajectories of the ions are used to identify the diffusion mechanism and quantify the diffusion properties. However, MD does require the accurate description of interatomic interactions, *i.e.* the potential energy surface (PES).[95,96]

In *ab initio* MD (AIMD) simulations, the interactions between atoms are described by first-principles methods such as density functional theory (DFT), providing high reliability and accuracy as well as great transferability. However, due to its high computational expenses, AIMD is only feasible for small systems in terms of length scale (<1000 atoms) and timescale

(~100 ps) limiting the number of diffusion events.[95,96] As a result, diffusion properties estimated from AIMD simulations are often compromised by poor statistics and require high simulation temperatures to ensure a sufficient number of ion jumps.[95,97]

In contrast, classical force field MD (FFMD) simulations employ interatomic potentials to model the interactions between the ions. The PES is described as a function of the atom positions rather than a variational ground state energy as in AIMD, which significantly reduces computational demands. Consequently, FFMD simulations are amenable for larger systems with up to millions of ions and longer simulation times (>1 ns), resulting in lower statistical variances in the determined diffusion properties. However, the accuracy of FFMD simulations depends on the availability and suitability of the FF parameter sets, which are usually restricted to a limited number of compounds and properties.[95,96]

To tackle the trade-off between accuracy and efficiency in MD simulations, Kobayashi *et al.* introduced a high-throughput method for producing reliable FFs using a metaheuristic Cuckoo Search (CS) approach based on structure information from first-principles calculations. In this way, low-cost and accurate FFMD simulations are ensured.[98,99]

It should be noted that data-driven machine learning potentials (MLP) has emerged as a powerful tool for materials exploration and development, providing an alternative to AIMD and classical FFMD simulations.[100–104] In particular, Neural Network Potentials (NNPs) have been demonstrated to reproduce AIMD results with high accuracy.[105,106] However, NNPs evaluate energy and forces in a purely empirical manner, which requires large amounts of training data. Additionally, their use in extrapolated spaces, beyond the training set, presents challenges. In contrast, the FF employed in this study, based on a physical model, is expected to maintain a higher degree of consistency even in extrapolated spaces. Moreover, NNPs face limitations in terms of computational time. For instance, in this study, the simulation of 1 ns (10^6 steps) of a system with approximately 3500 atoms requires about 12 hours on 2 CPU cores. By comparison, performing the same calculation using M3GNet.py,[107,108] which is known for its relatively fast performance,[109,110] along with the Atomic Simulation Environment (ASE)[111] on 16 CPU cores, requires 458 hours. Thus, FFMD simulations are considered advantageous for studies that comprehensively evaluate a large number of compositions at multiple temperatures.

Here, DFT based FFMD simulations of $Na_{1+x+y}Sc_yZr_{2−y}Si_xP_{3−x}O_{12}$ ($0 \leq x \leq 3$; $0 \leq y \leq 2$), an example of a promising NaSICON compound, are performed to comprehensively investigate the Na^+ transport behavior in multi-substituted NaSICONs. Initially, the FF parameters are optimized with the CS algorithm leveraging structural information acquired from short AIMD simulations of a training system. We show that the FF parameters obtained for the training system with a specific composition can be transferred to target systems with arbitrary compositions. The optimized potential parameters are then employed in the subsequent FFMD simulations across the entire compositional range of $Na_{1+x+y}Sc_yZr_{2−y}Si_xP_{3−x}O_{12}$. Na^+

diffusion coefficients are derived from the collective diffusion events described by their mean squared displacement. In addition, estimated radial distribution functions are analyzed to understand the influence of Sc^{3+}- and Si^{4+}-substitutions on the Na^+ transport behavior.

On the one hand, this study aims to deepen the understanding of the influences of multi-element substitution on the transport of Na^+ in NaSICONs, all in pursuit of achieving high ionic conductivity for ASS-NIBs applications. On the other hand, this study showcases the efficacy of the applied methodology for large-scale screening, enabling the exploration of extensive configurational spaces of NaSICONs and other materials promising as SSEs.

2. Methods

2.1 Force field model

FFMD simulations of Na^+ diffusion in $Na_{1+x+y}Sc_yZr_{2-y}Si_xP_{3-x}O_{12}$ require an FF model that describes the ion pair interactions and structural framework of NaSICONs. Thus, the FF model proposed by Kobayashi *et al.*[99] is applied, which consists of two-body potentials[112,113] and three-body angular potentials.[114]

The Morse potential is applied to describe the attractive interactions and short-range repulsions of cation–anion pairs,[112]

$$\varphi_{ij}^{\text{Morse}}\left(r_{ij}\right) = D_{0,ij}\left\{e^{\left[2\alpha_{ij}\left(r_{0,ij}-r_{ij}\right)\right]} - 2e^{\left[\alpha_{ij}\left(r_{0,ij}-r_{ij}\right)\right]}\right\} \quad (1)$$

where $D_{0,ij}$ is the equilibrium well depth defined by dissociation energy, α_{ij} describes the width of the potential associated to the bond softness, r_{ij} is the distance and $r_{0,ij}$ the equilibrium distance between the ith and j^{th} ion.

The screened Coulomb potential is added to account for the repulsive interactions among cations or anions. Since the Coulomb potential prevents cation or anion pairs with a small distance, their short-range repulsion can be neglected,[112]

$$\varphi_{i_1i_2}^{\text{Coul}}(r_{i_1i_2}) = \frac{1}{4\pi\varepsilon_0}\frac{q_{i_1}q_{i_2}}{r_{i_1i_2}}\text{erfc}\left(\frac{r_{i_1i_2}}{\rho_{i_1i_2}}\right) \quad (2)$$

where ε_0 is the permittivity of the vacuum, q_{i_1} and q_{i_2} are the formal charges of ions i_1 and i_2, and $r_{i_1i_2}$ is their ionic distance. The included complementary error function $\text{erfc}\left(\frac{r_{i_1i_2}}{\rho_{i_1i_2}}\right)$ is a function of the ion distances over the screening length $\rho_{i_1i_2} = f(r_{i_1} + r_{i_2})$, which is determined by the sum of the effective radii r_{i_1} and r_{i_2} of the ions i_1 and i_2 and the screening factor f defining the radius of the Coulomb potential.

To avoid discontinuities in the potential energy and force, the following smoothing function with the cutoff radius r_c^{2b} is applied to both the Morse and Coulomb pair potential:

$$\tilde{\varphi}(r) = \varphi(r) - \varphi\left(r_c^{2b}\right) - \left(r - r_c^{2b}\right)\frac{d\varphi(r)}{dr}\bigg|_{r=r_c^{2b}} \quad (3)$$

In addition, the Stillinger–Weber (SW) angular potential is applied to describe the framework of the non-migrating cations and oxygen anions,[114]

$$\varphi_{ijk}^{\text{SW}}\left(r_{ij},\ r_{jk},\ \theta_{ijk}\right) = \lambda_{0,ijk}e^{\left[\left(\frac{1}{r_{ij}-r_c^{3b}}\right)+\left(\frac{1}{r_{jk}-r_c^{3b}}\right)\right]}\left(\cos\theta_{ijk}+\gamma_{0,ijk}\right)^2 \quad (4)$$

where r_{ij} and r_{jk} are the ionic distances and θ_{ijk} is the angle between the ith, j^{th}, and k^{th} ion. $\lambda_{0,ijk}$ is the equilibrium depth of the potential well and $\gamma_{0,ijk}$ is the equilibrium angle between the ith, j^{th} and k^{th} ion. The cutoff radius r_c^{3b} ensures that only nearest neighbor configurations are considered.

In previous studies, this FF model has been successfully applied to other solid state materials, such as $LiZr_2(PO_4)_3$,[99,115] $La_{(1-x)/3}Li_xNbO_3$,[116] $LiAl_5O_8$,[117] Li_3MCl_6,[118] and $La_{1-x}M_xF_{3-x}$,[99] demonstrating rapid FF production with sufficient accuracy, as described below.

2.2 Force field parameterization

The FF parameters $D_{0,ij}$, α_{ij} and $r_{0,ij}$ of the Morse potential, $\rho_{i_1i_2}$ of the Coulomb potential, and λ_{ijk} and γ_{ijk} of the SW potential must be determined for the $Na_{1+x+y}Sc_yZr_{2-y}Si_xP_{3-x}O_{12}$ system. Thus, FF parametrization was conducted using a training system with 120 atoms according to the following steps:

(i) AIMD simulations were performed to obtain the equilibrium volume (V_0), the radial distribution function (RDF) and the bond angular distribution function (ADF) by averaging the ionic configurations of every 10th step, omitting the first 800 steps to ensure that the system is in equilibrium.

The RDF $g_{ij}(r)$ describes the particle density as a function of the distance r from the reference atom i to a surrounding atom j according to eqn (5),

$$g_{ij}(r) = \frac{1}{4\pi r^2}\frac{1}{N_i}\sum_i^{N_i}\sum_{j>i}^{N_j}\left[\delta\left(r-r_{ij}\right)\right] \quad (5)$$

with N_i and N_j being the numbers of the ions i and j, respectively.

The ADF $h_{ijk}(\theta)$ describes the particle density as a function of the bond angle θ_{ijk} between the reference atom i and two other atoms j and k within a given distance (2.8 Å) according to eqn (6),

$$h_{ijk}(\theta) = \frac{1}{N_i}\sum_i^{N_i}\sum_{j>i}^{N_j}\sum_{k>j>i}^{N_k}\left[\delta\left(\theta-\theta_{ijk}\right)\right] \quad (6)$$

with N_i, N_j and N_k being the numbers of the ion i, j and k, respectively.

Both RDF and ADF are determined by averaging the same element combinations, such as Sc–O, Zr–O, Si–O, P–O, and O–Sc–O, O–Zr–O, O–Si–O, O–P–O for $Na_{1+x+y}Sc_yZr_{2-y}Si_xP_{3-x}O_{12}$. The RDF, ADF and V_0 are used as reference data in the subsequent FF fitting process.

(ii) The metaheuristic optimization of the FF parameters was performed by the CS algorithm[119–121] employing the AIMD reference data obtained in step (i).[98,99] The hyperparameters in the CS algorithm are the number of individuals (nests) in each generation (N_n) and the fraction of individuals replaced in the next generation by nests with new random solution (P_n).[121]

(iii) To evaluate the optimization process, FFMD simulations were performed using the obtained FF parameters. The results

of the simulations were analyzed in the same way as for AIMD in step (i). The optimization process was checked for consistency using the loss function L assessing the differences between the RDF, ADF, and V_0 values obtained by FFMD and AIMD simulations (eqn (S1)–(S4) in ESI†).[122]

Step (ii) and (iii) were repeated until the loss function value met the defined convergence criteria.[98,99]

2.3 Force field molecular dynamics simulations and analysis

With the optimized FF parameters, FFMD simulations were performed for a total of 119 compositions of $Na_{1+x+y}Zr_{2-y}Sc_ySi_xP_{3-x}O_{12}$ ($0 \leq x \leq 3$; $0 \leq y \leq 2$) in the temperature range of $298 \leq T/K \leq 798$ in 100 K steps.

From the FFMD simulations, the mean squared displacement MSD of the migrating Na^+ (eqn (7)) is obtained, which is used to determine the tracer diffusion coefficient D^* (eqn (8)):

$$MSD = \sum_{i=1}^{N} \frac{\left\langle |r_i(t) - r_i(0)|^2 \right\rangle}{N} \quad (7)$$

$$D^* = \frac{1}{2d} \lim_{t \to \infty} \frac{MSD}{t} \quad (8)$$

where $r_i(t)$ and $r_i(0)$ represent the position of ion i at time t and at $t = 0$, respectively, N is the number of mobile ions, d is the dimension of diffusion. D^* describes the macroscopic ion transport and is related to the long-range diffusion coefficient D_σ by the Haven ratio H_R, which indicates the correlation of the trajectories of the migrating ions:[95,96]

$$D^* = H_R D_\sigma \quad (9)$$

D_σ is described by the Nernst–Einstein relation:

$$D_\sigma = \frac{u_i k_B T}{q_i} \quad (10)$$

where u_i is the mobility and q_i is the charge of ion i, T is the temperature, and k_B is the Boltzmann constant. The mobility of the ion i characterizes its conductivity $\sigma_i = u_i q_i c_i$ with c_i being the ion concentration.

Assuming $H_R = 1$, which is expected to have minimal impact on the results, the ionic conductivity is determined using the MSD, and the activation energy E_A is derived from the Arrhenius relationship:

$$\sigma_i T = \frac{q_i^2 c_i}{k_B} D^* = A e^{-\frac{E_A}{k_B T}} \quad (11)$$

Hereafter, D^* will be referred to as D for simplicity.

2.4 Computational details

2.4.1 Ab initio molecular dynamics. NpT-AIMD simulations of the training system $Na_3ScZrSiP_2O_{12}$, containing 120 atoms, were performed for 7 ps with 1 fs time steps at 298 K to collect the data for the FF parameter fitting. The calculations were conducted based on Kohn–Sham DFT[123,124] using the Vienna *Ab initio* Simulation Package (VASP).[125–128] In the AIMD

simulations the Parrinello–Rahman method with the Langevin thermostat was employed.[129,130] The generalized gradient approximation (GGA) functional parametrized by Perdew–Burke–Ernzerhof (PBEsol)[131] was used. The projected augmented wave method (PAW)[132,133] was applied and plane waves[128] with an energy cut-off of 520 eV were employed. The electronic convergence criterion was set to 10^{-5} eV. To sample the Brillouin zone, a $2 \times 2 \times 2$ gamma centered k-point mesh was used, following the Monkhorst and Pack scheme.[134] The $2p^63s^1$ electrons of sodium, $2s^22p^4$ electrons of oxygen, $3s^23p^63d^14s^2$ electrons for scandium, $4s^24p^64d^25s^2$ electrons of zirconium, $3s^23p^2$ electrons of silicon and $3s^23p^3$ electrons of phosphorus were treated as valence electrons.

2.4.2 CS optimization. FF parameters of the Morse, Coulomb and SW potentials were determined using the Nagoya Atomistic Simulation Package (NAP).[98,99] The two- and three-body cutoff radii were set to $r_c^{2b} = 7.0$ Å and $r_c^{3b} = 3.0$ Å, respectively. The hyperparameters of the CS optimization were set to $N_n = 36$ and $P_n = 0.25$.

2.4.3 Force field molecular dynamics. All FFMD simulations were performed in cells with random Sc/Zr and Si/P arrangement using NAP.[98,99] Initial NpT-FFMD simulations of the training system $Na_3ScZrSiP_2O_{12}$, containing 120 atoms, were performed for 20 ps with 2 fs time steps at 298 K to validate the CS-derived FF parameters.

With the optimized FF parameters, FFMD simulations of supercells with composition $Na_{1+x+y}Zr_{2-y}Sc_ySi_xP_{3-x}O_{12}$ ($0 \leq x \leq 3$; $0 \leq y \leq 2$) with up to 4013 atoms were performed in the temperature range of $298 \leq T/K \leq 798$ in 100 K increments. First, NpT-FFMD simulations were conducted for 10 ps with 1 fs time steps to optimize the cell volume. Subsequently, NVT-FFMD simulations were performed for 1 ns with 1 fs time steps.

The Langevin thermostat, with a relaxation time of 50 fs, was used to control the temperature in both the NpT and NVT ensembles. For pressure regulation in the NpT ensemble, the Berendsen barostat with isotropic coupling and a relaxation of 50 fs was employed. To evaluate the influence of the thermostat on ionic diffusion, additional FFMD simulations were conducted under the NVE ensemble, omitting a heat bath. These simulations show that the diffusion coefficients increase by approximately a factor of 1.4 on average (Fig. S1†). Nevertheless, the overall trend of concentration-dependent diffusion behavior remains largely unchanged.

3. Results

3.1 Validation of optimized force field parameters

The optimization of the FF parameters of the six-component NaSICON structure $Na_{1+x+y}Sc_yZr_{2-y}Si_xP_{3-x}O_{12}$ follows a multiple-step process detailed in Section 2 of the ESI.† The FF parameters were optimized using the training system Na_3-$ScZrSiP_2O_{12}$. For further validation, the obtained FF parameters are applied in FFMD simulations across the entire compositional range of $Na_{1+x}Zr_2Si_xP_{3-x}O_{12}$ ($0 \leq x \leq 3$) at 598 K and the resulting conductivities are compared with literature values. These compositions and temperature are chosen due to the extensive data available in the literature, allowing
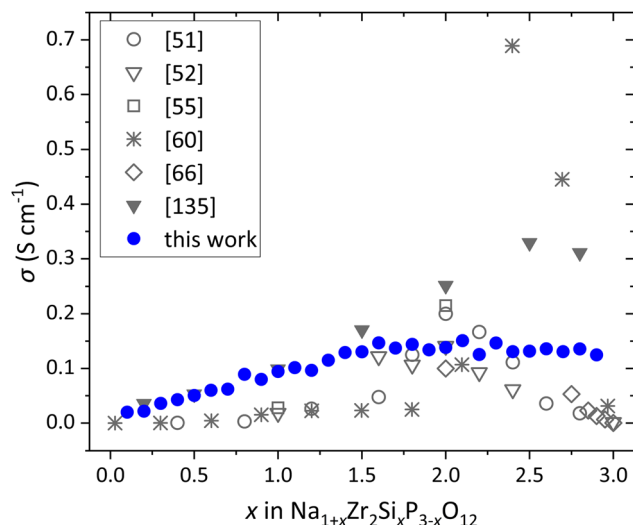
Fig. 2 Comparison of Na$^+$ conductivity of Na$_{1+x}$Zr$_2$Si$_x$P$_{3-x}$O$_{12}$ ($0 \leq x \leq$ 3) at 598 K obtained by FFMD simulations using FF parameters derived from the CS optimization in the Na$_3$ScZrSiP$_2$O$_{12}$ training system with literature data obtained from experimental studies[51,52,55,66] and KMC simulations[60,135] at 573 K.

a comprehensive comparison. Fig. 2 shows the comparison of the resulting conductivities with literature data from experiments and KMC simulations.[51,52,60,66,135] Although, the data in the literature exhibit significant variation that exceed the uncertainty of the simulation, the conductivities obtained from FFMD simulations in this work and the literature data show similar dependence on the substitution degree x. This indicates that the FF parameters not only adequately describe the NaSICON structure but also capture the interactions between the migrating Na$^+$ and both the structural framework and the neighboring Na$^+$, which are crucial for the Na$^+$ transport in NaSICONs, as highlighted in our previous studies.[135,136] It is shown that the parameters originally obtained for the training system with the specific composition Na$_3$ScZrSiP$_2$O$_{12}$ can be applied to the entire compositional range of Na$_{1+x+y}$Sc$_y$Zr$_{2-y}$Si$_x$P$_{3-x}$O$_{12}$.

3.2 Microscopic Na$^+$ diffusion

Since the optimized FF parameter adequately describe the NaSICON system, NVT-MD simulations are conducted using this FF parameter set (Table S3†) to investigate the Na$^+$ diffusion behavior in Na$_{1+x+y}$Zr$_{2-y}$Sc$_y$Si$_x$P$_{3-x}$O$_{12}$ ($0 \leq x \leq 3$; $0 \leq y \leq 2$) over the temperatures range of $298 \leq T/K \leq 798$. Information about the microscopic Na$^+$ diffusion behavior can be directly obtained from the MD simulations.

Fig. 3 depicts the resulting density plot of the accumulated trajectories of the Na$^+$ in Na$_3$Sc$_{1.5}$Zr$_{0.5}$Si$_{0.3}$P$_{2.7}$O$_{12}$ over the simulation time, revealing the well-connected three-dimensional Na$^+$ diffusion pathways between the Na1 and Na2 sites that enable the long-range Na$^+$ transport. This conduction pathway is in excellent agreement with the findings of Deng *et al.*,[137] who used a combination of FFMD simulations with parameters of the interatomic potentials developed by
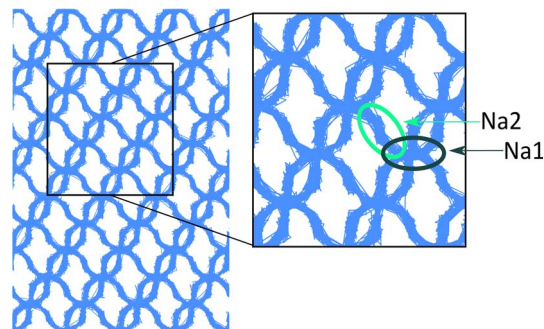

Fig. 3 The density plot of the accumulated trajectories of Na$^+$ ions in Na$_3$Sc$_{1.5}$Zr$_{0.5}$Si$_{0.3}$P$_{2.7}$O$_{12}$ over the MD simulation time. The close-up view shows the well-connected diffusion pathways between the Na1 (light green) and the Na2 (dark green) sites.

Pedone *et al.*,[138] bond valence energy landscape method, maximum-entropy method/Rietveld analysis method.

Fig. 4a depicts the resulting MSDs of the Na$^+$ in Na$_3$Sc$_{1.5}$Zr$_{0.5}$Si$_{0.3}$P$_{2.7}$O$_{12}$ at all simulation temperatures. In Fig. 4b, the MSDs of all other ions in the same compound are shown for 698 K. As anticipated, solely the Na$^+$ diffuse in the cell, whereas O^{2-}, Sc^{3+}, Zr^{4+}, Si^{4+}, P^{5+} vibrate around their initial equilibrium sites.

3.3 Exploration of the configurational space

The microscopic Na$^+$ diffusion behavior is accurately captured using the optimized FF parameter set. Consequently, the diffusion coefficient, conductivity, and activation energy are predicted across the entire configurational space of Na$_{1+x+y}$Sc$_y$Zr$_{2-y}$Si$_x$P$_{3-x}$O$_{12}$ ($0 \leq x \leq 3$; $0 \leq y \leq 2$). As most current studies focus on only a few compositions, this comprehensive prediction offers a broader picture of Na$^+$ diffusion in the Sc^{3+}- and Si^{4+}-substituted NaSICON system.

The Na$^+$ tracer diffusion coefficients D are calculated using the MSDs according to eqn (8). Following the approach proposed by Usler *et al.*,[139] the error $u(D)$ in D is estimated, indicating that $u(D)$ is two orders of magnitude smaller than D for temperatures above 498 K. Fig. S9† illustrates the Arrhenius plots for various compositions with different substitution ratios and Na$^+$ concentrations, showing the anticipated linear relationship between D and temperatures above 498 K. Below this temperature, however, deviations from the linearity are observed, probably due to insufficient statistics of Na$^+$ hopping events. The Na$^+$ conductivities σ and activation energies E_A are derived from eqn (11). For the determination of E_A, only diffusion coefficients obtained at temperatures between $498 \leq T/K \leq$ 798 are considered to ensure a statistically significant number of Na$^+$ jumps. The calculated values of D and σ at 598 K, E_A and the cell volumes V of Na$_{1+x+y}$Sc$_y$Zr$_{2-y}$Si$_x$P$_{3-x}$O$_{12}$ ($0 \leq x \leq 3$; $0 \leq y \leq 2$) are depicted in Fig. 5. Note that the Na$^+$ diffusion coefficients and conductivities are shown for 598 K rather than room temperature because the conductivity values below 498 K fall within the extrapolated range. Additionally, 598 K is particularly relevant for practical applications, as it corresponds to the operating temperature of NAS batteries.[140]
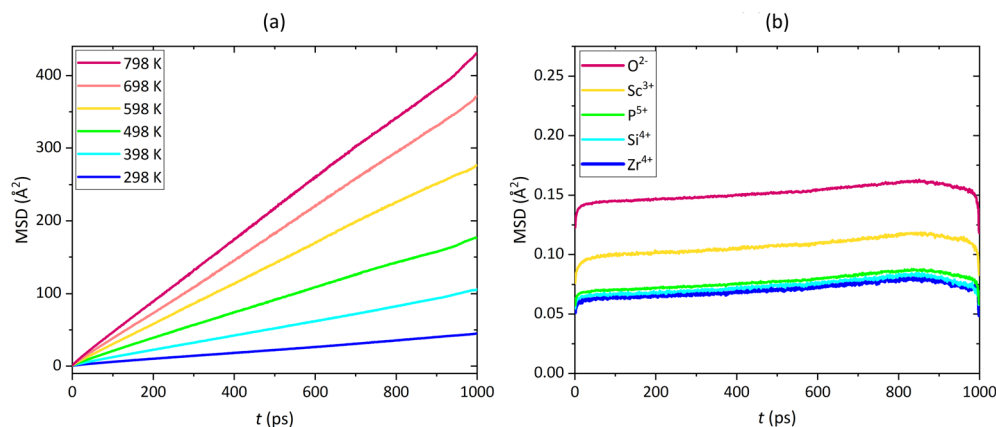
Fig. 4 MSD of (a) Na^+ in the temperature range of $298 \leq T/K \leq 798$ and (b) O^{2-}, Sc^{3+}, Zr^{4+}, Si^{4+}, P^{5+} at 698 K in $Na_3Sc_{1.5}Zr_{0.5}Si_{0.5}P_{2.5}O_{12}$.
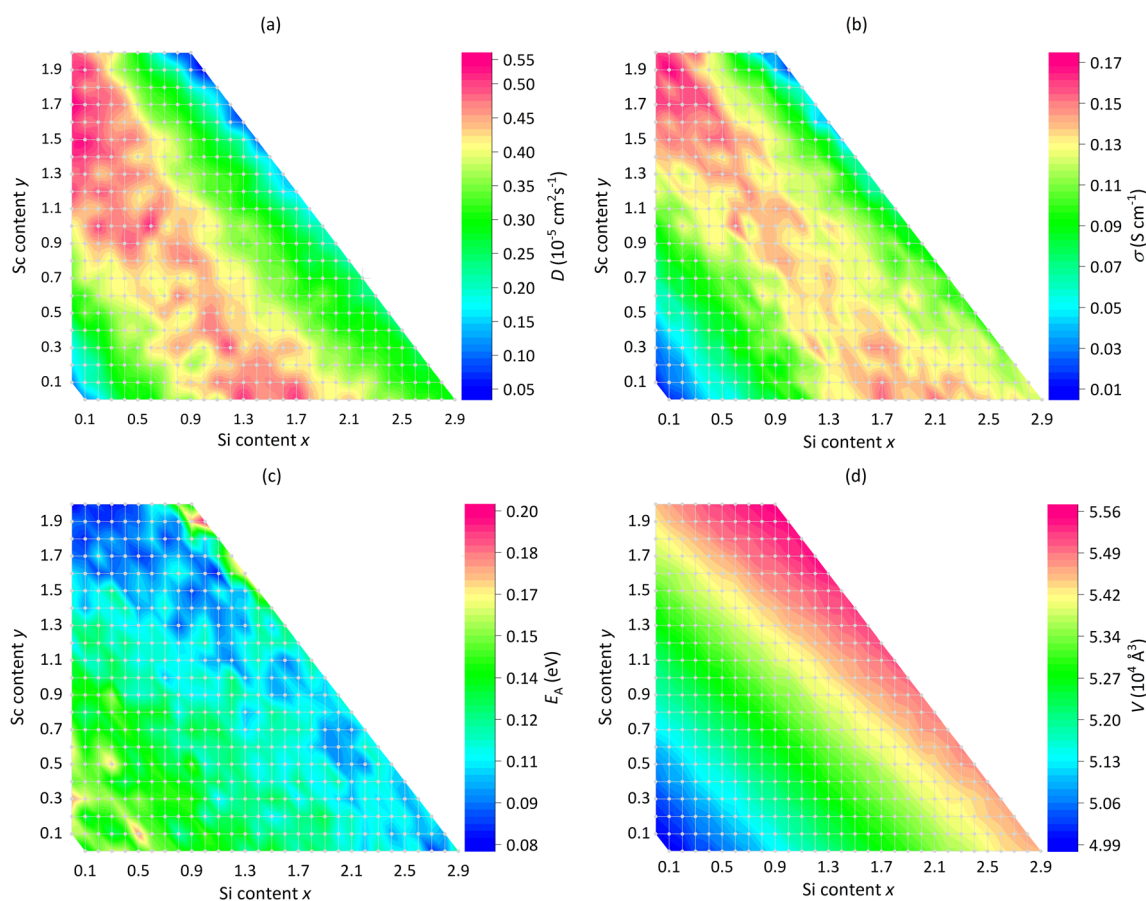

Fig. 5 (a) Na^+ tracer diffusion coefficient D at 598 K, (b) Na^+ conductivity σ obtained at 598 K, (c) activation energy E_A obtained from D at temperatures between $498 \leq T/K \leq 798$, and (d) cell volume V as a function of the Sc^{3+}-content y and Si^{4+}-content x in $Na_{1+x+y}Zr_{2-y}Sc_ySi_xP_{3-x}O_{12}$.

It is noted that in this study, the Sc/Zr and Si/P arrangements were randomly configured, and thus the impact of such cation arrangements on the diffusion coefficient of Na^+ are investigated. For ten randomly selected compositions, four random initial arrangements were created and the relative deviation of the diffusion coefficient among these was evaluated. The distribution of the obtained diffusion coefficients is shown in

Fig. S10.† The variation in diffusion coefficients due to differences in arrangement are very small, with the relative standard error being a maximum of 5.6% and an average of 2.6% across the 10 compositions. Therefore, it is concluded that the supercell size and simulation time (1 ns) applied in this study are sufficiently large.

In our previous studies on $Na_{1+x}M_2Si_xP_{3-x}O_{12}$, we have revealed the dependence of the Na^+ mobility in NaSICONs on both the local ionic environment of the Na^+ lattice sites and the Na^+ migration energy.[135,136] The introduction of Si^{4+}-substituents on P^{5+} sites corresponds to a charged defect of -1, leading to favorable Na^+–Si^{4+} pair interactions which influence the Na^+ mobility. Three compositional ranges in $Na_{1+x}M_2Si_xP_{3-x}O_{12}$ can be distinguished:

(i) At small substitution concentrations ($x < 0.5$), there are only a few Na^+ charge carriers, that are trapped in low energy states near the introduced Si^{4+} due to the attractive Na^+–Si^{4+} interactions. The depth and number of traps increases with the number of Si^{4+}, resulting in low conductivities and an increase of the activation energies.

(ii) At intermediate to high substitution concentrations ($0.5 \leq x \leq 2.0$), Na^+ percolation pathways form between favorable Si^{4+}-rich positions. The Na^+ mobility is thus determined by the migration energy. As a result, the conductivity increases, and the activation energy decreases with substitution content.

(iii) At high substitution concentrations ($x > 2.0$), the insufficient number of vacant Na^+ lattice sites lead to a decrease in ionic conductivity while the activation energy is the lowest due to the low migration energy. However, strong unfavorable Na^+–Na^+ repulsion may lead to an increase in activation energy.

Accordingly, the behavior of D (Fig. 5a), σ (Fig. 5b), and E_A (Fig. 5c) can be described as a function of the substitution degree in $Na_{1+x+y}Sc_yZr_{2-y}Si_xP_{3-x}O_{12}$. In this system, the substitution of Sc^{3+} for Zr^{4+} and Si^{4+} for P^{5+} creates charged defects of -1. At minor substituents concentrations, both D and σ remain low, while E_A increases, although less pronounced than previously observed in $Na_{1+x}M_2Si_xP_{3-x}O_{12}$.[135] This behavior can be attributed to the limited number of Na^+ charge carriers being trapped in low energy states near the introduced Sc^{3+} and Si^{4+} ions. With increasing substitution level, percolation pathways form between Sc^{3+}- and Si^{4+}-rich environments, leading to an increase in both D and σ and a decrease in E_A. At high substitution concentrations, D and σ decrease due to the lack of available vacant Na^+ sites. But the activation energy is lowest, particularly in the single-substituted structures, as previously observed in $Na_{1+x}Zr_2Si_xP_{3-x}O_{12}$. Though, at high Sc^{3+}- and intermediate Si^{4+}-content, the activation energy is elevated. This can be attributed to strong Na^+–Na^+ repulsive interactions that prevent the occupation of Na^+ sites, as found in $Na_{1+x}Sn_2Si_xP_{3-x}O_{12}$.[135] In summary, the simulations reveal that the region of high diffusivity and conductivity follows a diagonal pattern, with increasing values observed at high Sc content ($1.3 \leq y \leq 1.9$) and medium to high Si content ($1.3 \leq x \leq 2.7$).

The comparison of σ (Fig. 5b) and E_A (Fig. 5c) with cell volume V (Fig. 5d) shows that there is no clear relation, suggesting that the enlargement of the bottleneck area with increased cell volume has a less pronounced impact on conductivity and activation energy than previously proposed in the literature.[49,50,55,65,74–76,78,79]

Earlier studies have already experimentally investigated some compositions of $Na_{1+x+y}Sc_yZr_{2-y}Si_xP_{3-x}O_{12}$. For example, Lunghammer et al. employed time-domain nuclear magnetic resonance (NMR) and broadband conductivity spectroscopy to investigate the Na^+ motion in the Si^{4+}-rich composition $Na_{3.4}Sc_{0.4}Zr_{1.6}Si_2PO_{12}$ on both short- and long-range scales revealing activation energies of 0.13 eV to 0.15 eV and 0.29 eV to 0.31 eV, respectively.[82] Rapid Na^+ exchange leads to ionic conductivities of 2×10^{-3} S cm^{-1} at 25 °C.[82] For the same composition, Ma et al. reported bulk conductivities of 6.2×10^{-3} S cm^{-1} at 298 K.[81] For the Sc^{3+}-rich composition $Na_{3.4}Sc_2Si_{0.4}P_{2.6}O_{12}$, Kaus et al. observed values of $E_A = 0.2$ eV and $\sigma = 4 \times 10^{-3}$ S cm^{-1} at 350 K using NMR relaxometry.[83] In a separate study, Guin et al. conducted impedance measurements on the same composition, reporting an activation energy of 0.14 eV, which corresponds to the bulk transport.[84] In comparison, MD simulations of this study yield values of $E_A = 0.11$ eV and $\sigma = 2.6 \times 10^{-2}$ S cm^{-1} at 298 K for the Si^{4+}-rich composition $Na_{3.4}Sc_{0.4}Zr_{1.6}Si_2PO_{12}$, and $E_A = 0.08$ eV and $\sigma = 1 \times 10^{-1}$ S cm^{-1} at 350 K for the Sc^{3+}-rich composition $Na_{3.4}Sc_2Si_{0.4}P_{2.6}O_{12}$. The values obtained for E_A in this study are consistent with the values for short-range bulk Na^+ transport, capturing the elementary diffusion processes involving local, correlated motions influenced by Coulomb interactions and structural disorder.[82] However, the obtained values for σ are one to two orders of
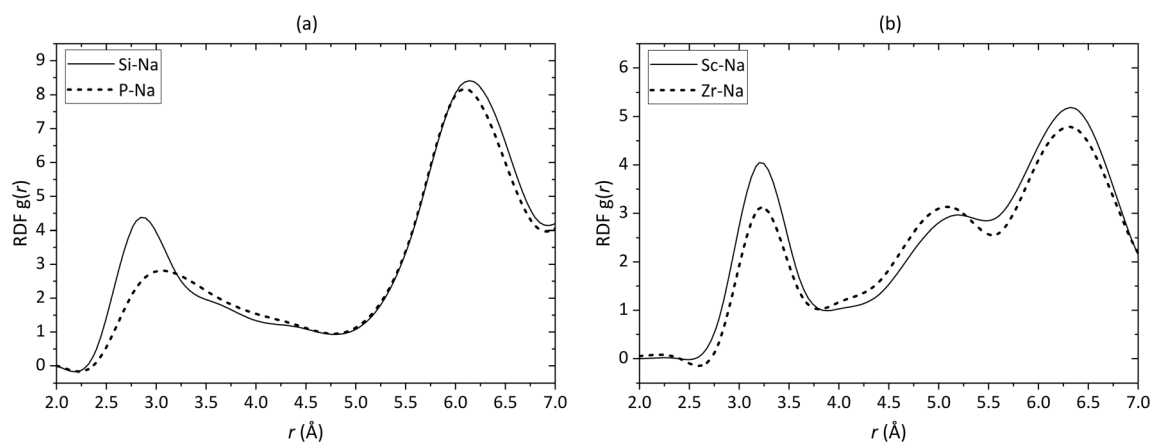

Fig. 6 Comparison of (a) RDFs of Si^{4+}–Na^+ (solid line) and P^{5+}–Na^+ (dashed line) in $Na_{1.5}Zr_2Si_{0.5}P_{2.5}O_{12}$ and (b) RDFs of Sc^{3+}–Na^+ (solid line) and Zr^{4+}–Na^+ (dash line) in $Na_{1.3}Sc_{0.3}Zr_{1.7}P_3O_{12}$.

magnitude higher than those reported in previously cited studies.[81–84] Nevertheless, our findings are in good agreement with the conductivities determined by Subramanian *et al.* at 573 K, using impedance measurements for various compositions, such as $\sigma = 1.35 \times 10^{-1}$ S cm^{-1} *versus* $\sigma = 1.07 \times 10^{-1}$ S cm^{-1} for $Na_3Sc_{0.5}Zr_{1.5}Si_{1.5}P_{1.5}O_{12}$.[90] Moreover, similar general behavior of conductivity and activation energy as a function of the substitution concentration have been reported in the literature for $Na_{3+y}Sc_yZr_{2-y}Si_2PO_{12}$ ($0 \le y \le 0.6$) and of $Na_{3+x}Sc_2Si_xP_{3-x}O_{12}$ ($0.05 \le x \le 0.8$).[81,84,94]

The effect of Sc^{3+}- and Si^{4+}-substitution on the Na$^+$ diffusion behavior in NaSICONs is further clarified by estimating RDFs of cations adjacent to the Na$^+$ sites. Fig. 6a illustrates der RDFs of Si^{4+}–Na$^+$ and P^{5+}–Na$^+$ in $Na_{1.5}Zr_2Si_{0.5}P_{2.5}O_{12}$. At smaller distances, the peak of the RDF of Si^{4+}–Na$^+$ pairs is larger compared to that of P^{5+}–Na$^+$ pairs, which indicates that more Na$^+$ are adjacent to Si^{4+} than to P^{5+}, suggesting the Na$^+$ trapping by the Si^{4+}-substituents.

Similarly, Fig. 6b shows the comparison of the RDFs of Sc^{3+}–Na$^+$ and Zr^{4+}–Na$^+$ pairs in $Na_{1.3}Sc_{0.3}Zr_{1.7}P_3O_{12}$. The RDF of Sc^{3+}–Na$^+$ pairs exhibit larger peak than that of Zr^{4+}–Na$^+$ pairs at small distances, indicating that the Na$^+$ are trapped by Sc^{3+} substituents.

4.   Conclusion

The Na$^+$ transport properties in NaSICONs were exhaustively investigated in $Na_{1+x+y}Sc_yZr_{2-y}Si_xP_{3-x}O_{12}$ ($0 \le x \le 3$; $0 \le y \le 2$) using FFMD simulations. For this purpose, FF parameters were determined based on the structural information of the training system $Na_3ScZrSiP_2O_{12}$ obtained from short AIMD simulations. The obtained FF parameters can be applied to target systems with arbitrary compositions, which they describe with performance comparable to DFT calculations. This underscores the effectiveness of the FF model in characterizing the structure and interactions in NaSICONs and in describing the Na$^+$ transport behavior without necessitating explicit consideration of the ion migration and transition state structure. In this way, the exhaustive exploration of the Na$^+$ transport in NaSICONs across a broad spectrum of compositions is feasible using fast, low-cost, and yet accurate FFMD simulations.

NVT-MD simulations revealed the three-dimensional diffusion pathways of Na$^+$ ions between the Na1 and Na2 sites. The resulting Na$^+$ diffusion coefficients D, ionic conductivities σ, and activation energies E_A show similar dependence on the substitution concentration as previously observed for the single-substituted structures $Na_{1+x}M_2Si_xP_{3-x}O_{12}$. The Na$^+$ transport behavior is primarily governed by the effects of Na$^+$ trapping and percolation caused by the introduced substituents. At minor substitution concentrations, Na$^+$ are trapped in low energy states near the substituents, resulting in low values of D and σ and high values of E_A. At intermediate substitution levels, Na$^+$ percolation pathways are formed, leading to an increase in D and σ and decrease in E_A. However, at very high substitution levels, D and σ decrease due to the lack of available Na$^+$ sites. Overall, the simulations indicate that the highest diffusivity and conductivity occur along a diagonal compositional trend, corresponding to elevated Sc contents ($1.3 \le y \le 1.9$) and moderate to high Si contents ($1.3 \le x \le 2.7$). The activation energies are found to be in good agreement with experimental values describing short-range Na$^+$ ion motions.

In addition, the Na$^+$ trapping effects of the introduced Sc^{3+}- and Si^{4+}-substitution was verified by estimating RDFs, providing further insights into the Na$^+$ migration behavior.

This study demonstrates the efficacy of the applied methodology in exploring large configurational spaces of NaSICONs and predicting promising materials for use in ASS-NIBs. The FFMD simulations, applying FF parameters optimized for the particular system under investigation, offer a computationally efficient way to identify substitution levels that lead to the highest conductivities. This allows further investigations to focus on this optimal range instead of exploring large compositional spaces. The key advantage of the applied method is its simplicity and versatility, making it applicable to a wide range of compounds and structures. In addition, the crucial impact of substitution in NaSICONs is further elucidated, indicating the high potential of these materials, especially $Na_{1+x+y}Sc_yZr_{2-y}Si_xP_{3-x}O_{12}$.

Data availability

The data supporting this article have been included as part of the ESI.† The raw data is available from the authors upon request.

Author contributions

Conflicts of interest

The authors declare no competing financial or non-financial interests.

Acknowledgements

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